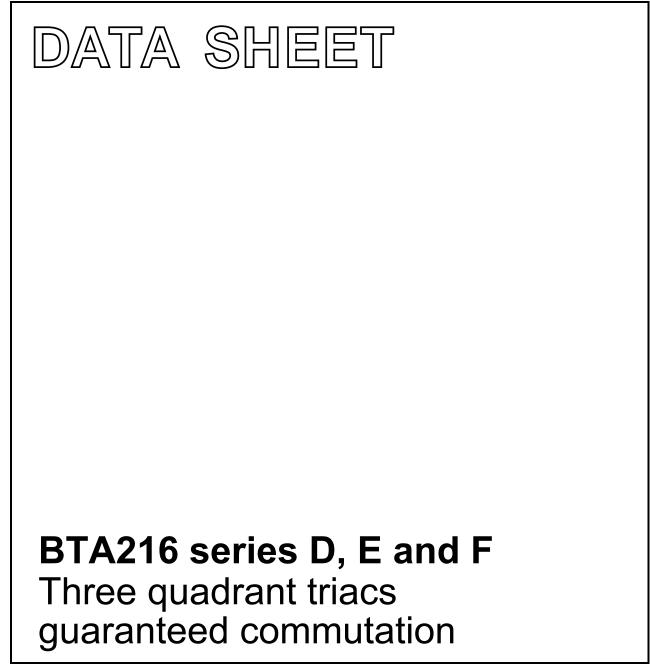
DISCRETE SEMICONDUCTORS



Product specification

September 2018



MAX.

600D

600E

600F

600

16

140

UNIT

٧

A

А

Three quadrant triacs guaranteed commutation

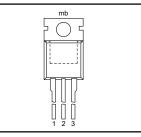
BTA216 series D, E and F

GENERAL DESCRIPTION

Passivated guaranteed commutation triacs in a plastic envelope intended for use in motor control circuits or with other highly inductive loads. balance These devices the requirements of commutation performance and gate sensitivity. The "sensitive gate" E series and "logic level" D series are intended for interfacing with low power drivers, including micro controllers.

PINNING - TO220AB

PIN T ta



QUICK REFERENCE DATA

current

PARAMETER

Repetitive peak off-state

Non-repetitive peak on-state

voltages RMS on-state current



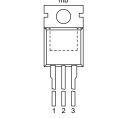
SYMBOL

BTA216-

BTA216-

BTA216-

IN	DESCRIPTION
1	main terminal 1
2	main terminal 2
3	gate
ab	main terminal 2



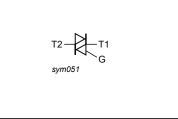
SYMBOL

 V_{DRM}

T(RMS)

PIN CONFIGURATION

ITSM



LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{DRM}	Repetitive peak off-state voltages		-	600 ¹	V
I _{T(RMS)} I _{TSM}	RMS on-state current Non-repetitive peak on-state current	full sine wave; $T_{mb} \le 99$ °C full sine wave; $T_i = 25$ °C prior to	-	16	A
l²t dI⊤/dt	I ² t for fusing Repetitive rate of rise of on-state current after	surge t = 20 ms t = 16.7 ms t = 10 ms $I_{TM} = 20 \text{ A}; I_G = 0.2 \text{ A};$ $dI_G/dt = 0.2 \text{ A}/\mu \text{s}$	- - -	140 150 98 100	Α Α Α²s Α/μs
I _{GM} P _{GM} P _{G(AV)} T _{stg}	triggering Peak gate current Peak gate power Average gate power Storage temperature	over any 20 ms period	- - - -40	2 5 0.5 150	A W W
T _j	Operating junction temperature		-	125	Ĵ Ĵ

¹ Although not recommended, off-state voltages up to 800V may be applied without damage, but the triac may switch to the on-state. The rate of rise of current should not exceed 15 A/µs.

Three quadrant triacs guaranteed commutation

BTA216 series D, E and F

THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
R _{th j-mb} R _{th j-a}	Thermal resistance junction to mounting base Thermal resistance junction to ambient	full cycle half cycle in free air	-	- - 60	1.2 1.7 -	K/W K/W K/W

STATIC CHARACTERISTICS

 $T_j = 25$ °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.		UNIT	
		BTA216-		D	E	F	
I _{GT}	Gate trigger current ²	$V_{\rm D} = 12 \text{ V}; \text{ I}_{\rm T} = 0.1 \text{ A}$ T2+ G+		Б	10	25	m A
		T2+ G-	-	5 5 5	10	25	mA mA
I _L	Latching current	T2- G- V _D = 12 V; I _{GT} = 0.1 A	-	-	10	25	mA
		T2+ G+ T2+ G- T2- G-		15 25 25	25 30 30	30 40 40	mA mA mA
I _H	Holding current	$V_{\rm D} = 12 \text{ V}; \text{ I}_{\rm GT} = 0.1 \text{ A}$	-	15	25	30	mA
					D, E, F		
V _T V _{GT}	On-state voltage Gate trigger voltage	$I_{T} = 20 \text{ A}$ $V_{D} = 12 \text{ V}; I_{T} = 0.1 \text{ A}$ $V_{D} = 400 \text{ V}; I_{T} = 0.1 \text{ A};$	- - 0.25		1.5 1.5 -		V V V
I _D	Off-state leakage current	$T_j = 125 °C$ $V_D = V_{DRM(max)}; T_j = 125 °C$	-		0.5		mA

DYNAMIC CHARACTERISTICS

 $T_i = 25$ °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS		MIN.		MAX.	UNIT
		BTA216-	D	E	F		
dV _D /dt	Critical rate of rise of off-state voltage	$V_{DM} = 67\% V_{DRM(max)};$ $T_j = 110 °C;$ exponential waveform; gate open circuit	30	60	70	-	V/µs
dl _{com} /dt	Critical rate of change of commutating current	$V_{DM} = 400 \text{ V}; \text{T}_{j} = 125 ^{\circ}\text{C};$ $I_{T(RMS)} = 16 \text{ A};$ $dV_{com}/dt = 10V/\mu\text{s}; \text{ gate}$ open circuit	2.5	6.2	18	-	A/ms
dl _{com} /dt	Critical rate of change of commutating current	$V_{DM} = 400 \text{ V}; \text{ T}_{j} = 125 ^{\circ}\text{C};$ $I_{T(RMS)} = 16 \text{ A};$ $dV_{com}/dt = 0.1 \text{ V}/\mu\text{s}; \text{ gate}$ open circuit	12	20	50	-	A/ms

² Device does not trigger in the T2-, G+ quadrant.

Ptot / W 25

20

15

10

5

0

0

BTA216 series D, E and F

Three quadrant triacs guaranteed commutation

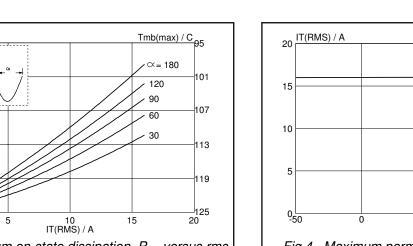
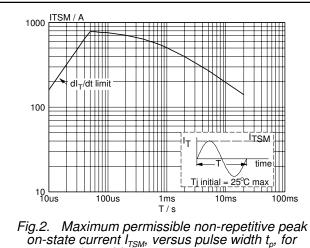
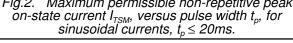
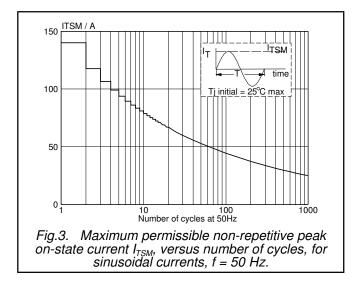
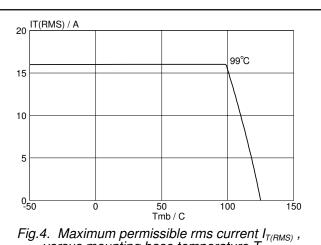


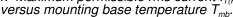
Fig.1. Maximum on-state dissipation, P_{tot} , versus rms on-state current, $I_{T(RMS)}$, where α = conduction angle.

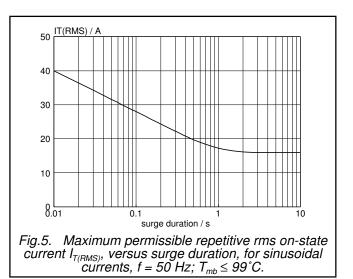


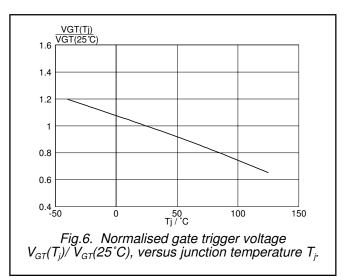












BTA216 series D, E and F

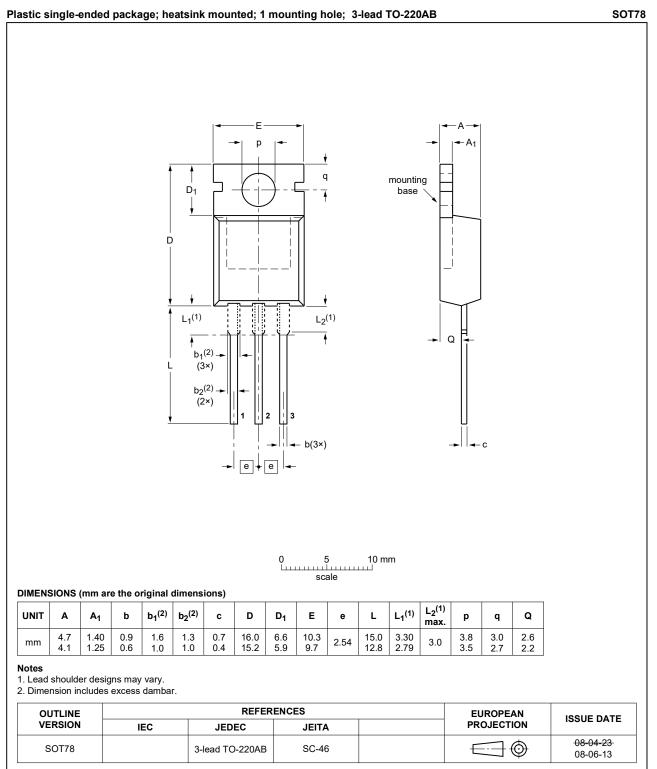
Three quadrant triacs guaranteed commutation

IT / A IGT(Tj) IGT(25°C) 50 Tj = 125 C Tj = 25 C 3 — T2+ G+ — T2+ Gtyp ma - T2- G-40 2.5 Vo = 1.195 V Rs = 0.018 Ohms 2 30 1.5 20 1 10 0.5 0 0 L 1.5 VT / V 150 0.5 2 2.5 3 -50 0 50 Tj/℃ 100 Fig.7. Normalised gate trigger current $I_{GT}(T_j)/I_{GT}(25^{\circ}C)$, versus junction temperature T_j . Fig.10. Typical and maximum on-state characteristic. 10 Zth j-mb (K/W) IL(Tj) IL(25°C) 3 25 1 bidirectional 2 0.1 1.5 → ^tp → 1 0.01 0.5 0.001 – 10us 0 -50 0.1ms 10ms 0.1s 1s 10s 50 Tj /℃ 100 1ms 0 150 tp/s Fig.11. Transient thermal impedance Z_{th j-mb}, versus Fig.8. Normalised latching current $I_L(T_i)/I_L(25^{\circ}C)$, versus junction temperature T_i pulse width $t_{\rm p}$. dlcom/dt (A/ms) IH(Tj) 100 3 IH(25°C) F TYPE E TYPE D TYPE 2.5 2 10 1.5 1 0.5 1 0 -50 50 Tj /℃ 20 40 60 100 120 140 100 150 80 Tj/°C 0 Fig.9. Normalised holding current $I_H(T_j)/I_H(25^{\circ}C)$, versus junction temperature T_j . Fig.12. Minimum, critical rate of change of commutating current dI_{com}/dt versus junction temperature, $dV_{com}/dt = 10V/\mu s$.

BTA216 series D, E and F

Three quadrant triacs guaranteed commutation

MECHANICAL DATA



Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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